



30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (SWP) (Type UX)

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _C = +25°C
	5.0mΩ @ V _{GS} = 10V	60A
30V	7.4mΩ @ V _{GS} = 4.5V	50A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

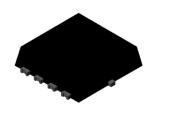
Features and Benefits

- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

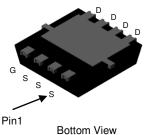
Mechanical Data

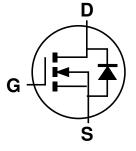
- Case: PowerDI[®]3333-8 (SWP) (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208@3
- Weight: 0.072 grams (Approximate)

PowerDI3333-8 (SWP) (Type UX)



Top View





Equivalent Circuit

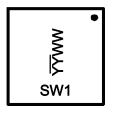
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3009LFVW-7	PowerDI3333-8 (SWP) (Type UX)	2,000/Tape & Reel
DMN3009LFVW-13	PowerDI3333-8 (SWP) (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



SW1 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digit of Year (ex: 17 = 2017)

WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	30	V	
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 7) V _{GS} = 10V	$T_C = +25$ °C $T_C = +70$ °C	Ι _D	60 48	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	90	Α	
Maximum Continuous Body Diode Forward Current (Note 7)	Is	60	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		I _{SM}	90	Α
Avalanche Current, L = 0.1mH (Note 8)		I _{AS}	33	Α
Avalanche Energy, L = 0.1mH (Note 8)	E _{AS}	58	mJ	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_D	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	126	°C/W
Total Power Dissipation (Note 6)		P_{D}	2.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	62	°C/W
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	4.6	C/VV
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

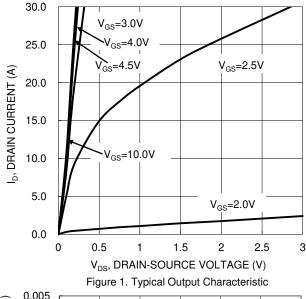
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	1	_	2.5	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance		_	3.5	5.0	mΩ	$V_{GS} = 10V, I_D = 30A$	
Static Drain-Source On-nesistance	R _{DS(ON)}	_	4.9	7.4	11177	$V_{GS} = 4.5V, I_D = 15A$	
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	2,000	_	рF	151111	
Output Capacitance	Coss	_	315	1	рF	$V_{DS} = 15V, V_{GS} = 0V,$ - f = 1MHz	
Reverse Transfer Capacitance	Crss	_	247	_	рF	1 = 1101112	
Gate Resistance	R_g	_	2.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	20	_	nC		
Total Gate Charge (V _{GS} = 10V)	Q_g	_	42	_	nC	V 15V L 15A	
Gate-Source Charge	Q_{gs}	_	4.7	_	nC	$V_{DS} = 15V, I_{D} = 15A$	
Gate-Drain Charge	Q_{gd}	_	7.4	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.9	_	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-On Rise Time	t _R	_	4.1	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	31	_	ns	$R_G = 3.3\Omega, I_D = 15A$	
Turn-Off Fall Time	t _F	_	15	_	ns	1	
Body Diode Reverse Recovery Time	t _{RR}	_	15	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	6.0	_	nC		

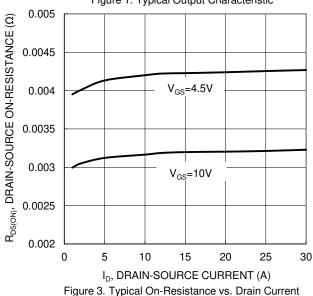
Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_{J} = +25^{\circ}C$.
- Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.









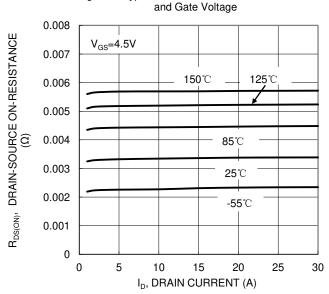
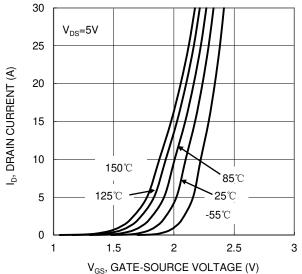
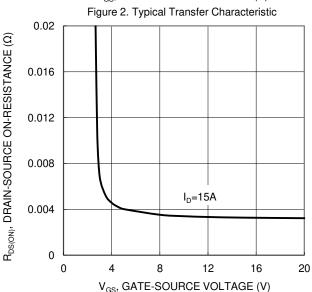


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





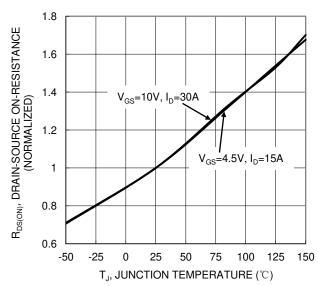


Figure 4. Typical Transfer Characteristic

Figure 6. On-Resistance Variation with Temperature



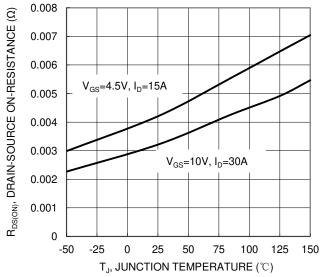


Figure 7. On-Resistance Variation with Temperature

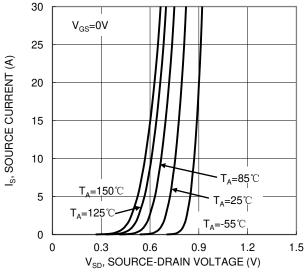
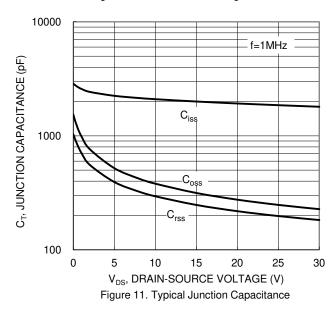


Figure 9. Diode Forward Voltage vs. Current



2 $V_{GS(TH)},$ GATE THRESHOLD VOLTAGE (V) 1.7 $I_D=1mA$ 1.4 1.1 $I_{D} = 250 \mu A$ 8.0 0.5 0.2 -50 -25 0 25 50 75 100 125 150 T_J, JUNCTION TEMPERATURE (°C)

Figure 8. Gate Threshold Variation vs. Junction Temperature

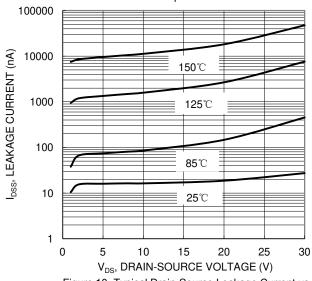


Figure 10. Typical Drain-Source Leakage Current vs. Voltage

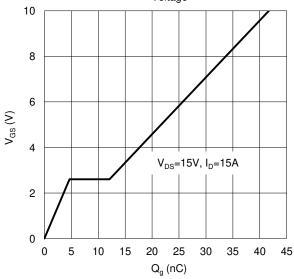
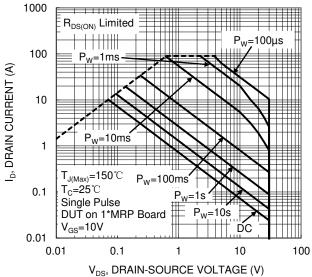


Figure 12. Gate Charge





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m V}_{
m DS}$, DRAIN-SOURCE VOLTAGE (V) Figure 13. SOA, Safe Operation Area

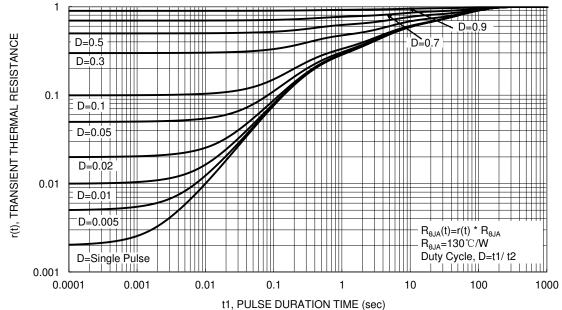


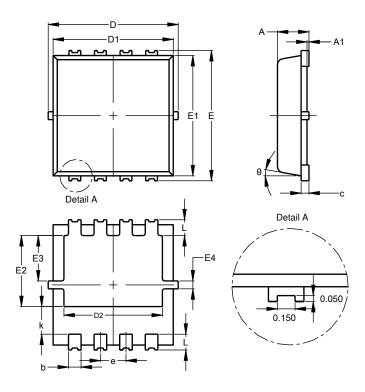
Figure 14. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

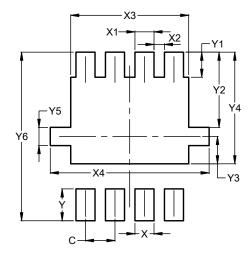


PowerDI3333-8 (SWP)						
(Type UX) ´						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A 1	0.00	0.05				
b	0.25	0.40	0.32			
C	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	-	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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